

Device Modeling Report

COMPONENTS:

DIODE/ SCHOOTTKY RECTIFIER / STANDARD

PART NUMBER: EC10QS10

MANUFACTURER: NIEC

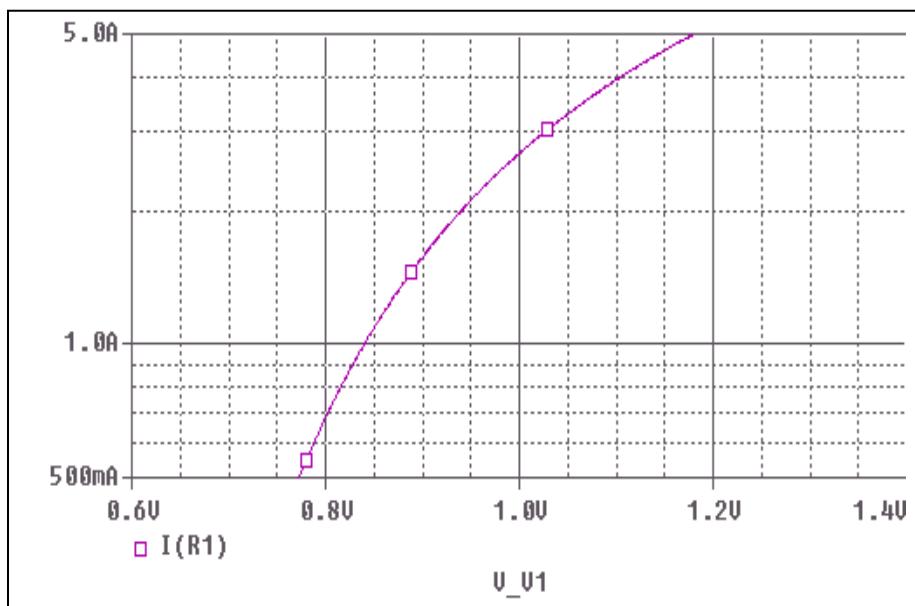


Bee Technologies Inc.

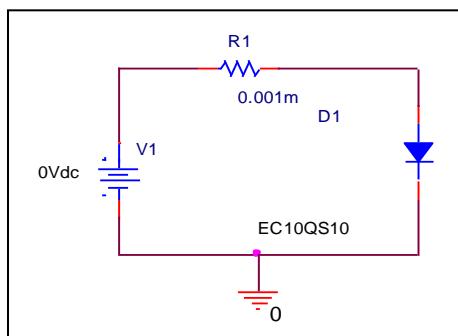
PSpice model parameter	Model description
IS	Saturation Current
N	Emission Coefficient
RS	Series Resistance
IKF	High-injection Knee Current
CJO	Zero-bias Junction Capacitance
M	Junction Grading Coefficient
VJ	Junction Potential
ISR	Recombination Current Saturation Value
BV	Reverse Breakdown Voltage(a positive value)
IBV	Reverse Breakdown Current(a positive value)
TT	Transit Time
EG	Energy-band Gap

Forward Current Characteristic

Circuit Simulation Result

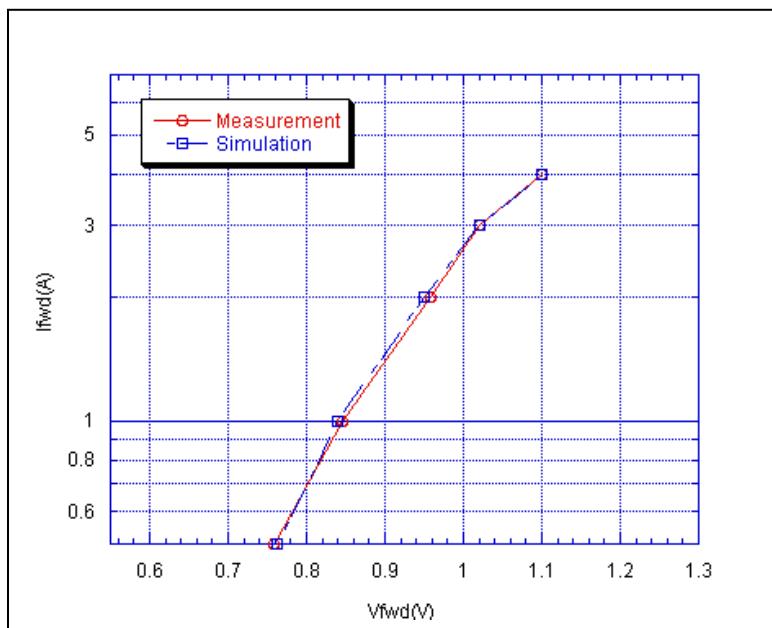


Evaluation Circuit



Comparison Graph

Circuit Simulation Result

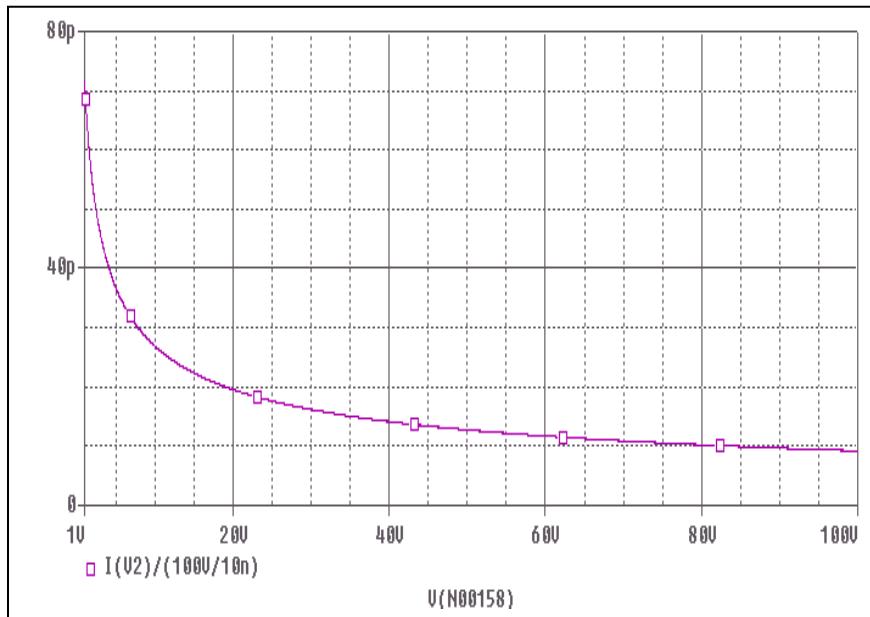


Simulation Result

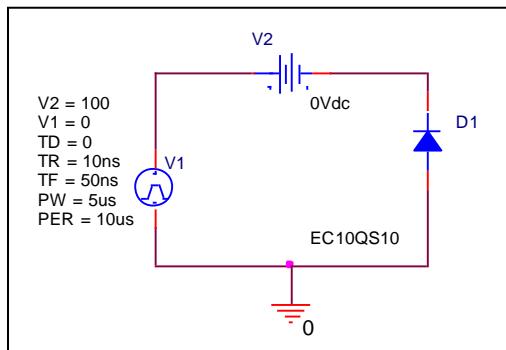
Ifwd(A)	Vfwd(V) Measurement	Vfwd(V) Simulation	%Error
0.5	0.759	0.763	0.53
1	0.845	0.840	-0.59
2	0.958	0.950	-0.84
3	1.020	1.010	-0.98
4	1.100	1.098	-0.18

Junction Capacitance Characteristic

Circuit Simulation Result

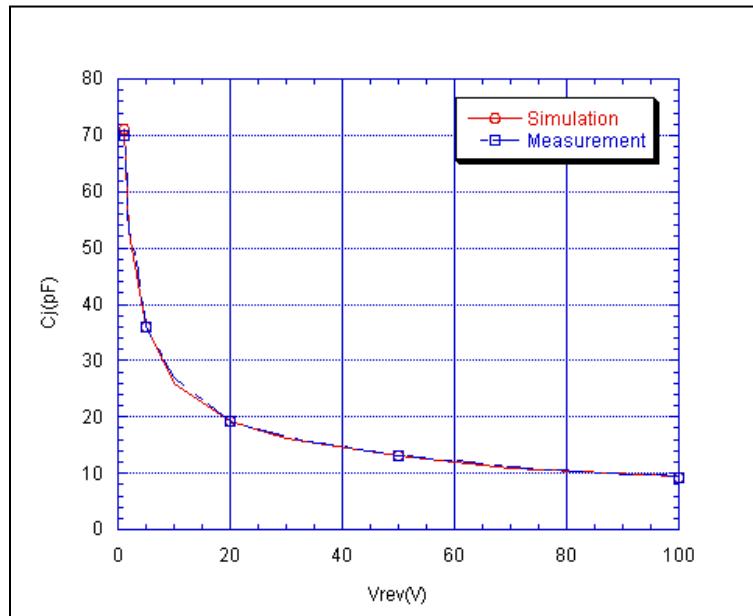


Evaluation Circuit



Comparison Graph

Circuit Simulation Result



Simulation Result

V_{rev} (V)	C_j (pF) Measurement	C_j (pF) Simulation	%Error
1	70.000	71.000	1.43
2	53.000	52.550	-0.85
5	36.000	35.875	-0.35
10	27.000	26.790	-0.78
20	19.300	19.200	-0.52
50	13.000	12.880	-0.92
100	9.200	9.110	-0.98